

Supporting Information

Conductance Switching in an Organic Material: From Bulk to Monolayer

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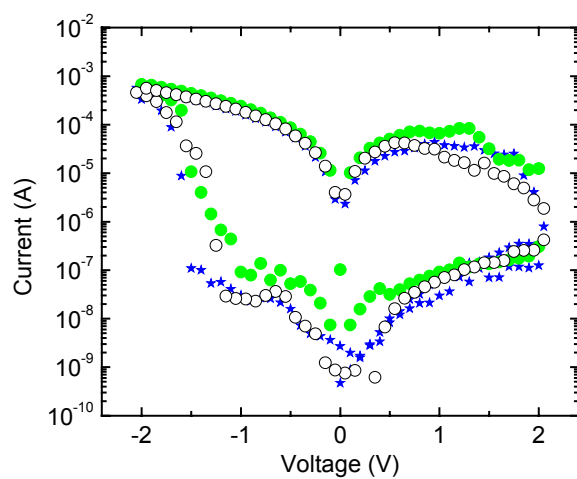


Figure S1. I - V characteristics of three devices based on fluorescein sodium:CNT (10 wt%) as represented by three different symbols.

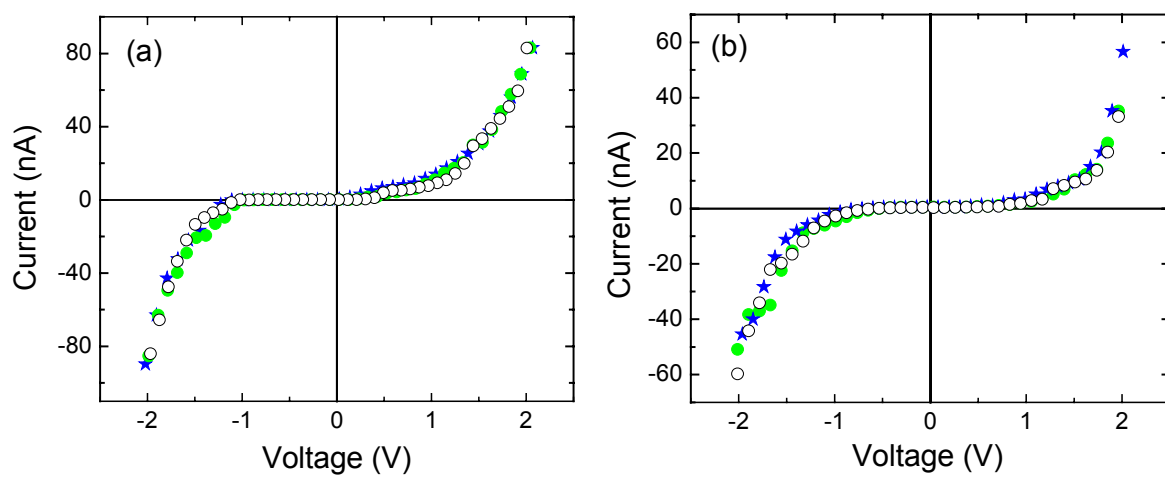


Figure S2. I - V characteristics with a STM tip of (a) native SiO_2 on Si and (b) monolayer of PAH at three different points.